NSN 5962-00-540-7821

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-00-540-7821
Body Length:
Between 0.745 inches and 0.765 inches
Body Width:
Between 0.275 inches and 0.295 inches
Body Height:
Between 0.227 inches and 0.247 inches
Maximum Power Dissipation Rating:
51.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Monolithic and hermetically sealed and negative outputs and positive outputs and w/open collector
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
13 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
03640-6088763 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization: Yes - demil/mli

NSN 5962-00-540-7821

Memory Microcircuit - Page 2 of 2



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